

KIA3402-VB Datasheet

N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)			
30	0.030 at V _{GS} = 10 V	6.5	4.5 nC			
30	0.033 at V_{GS} = 4.5 V	6.0	4.5110			

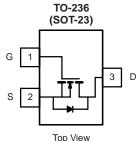
FEATURES

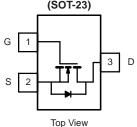
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET ٠
- 100 % R_g Tested ٠
- Compliant to RoHS Directive 2002/95/EC ٠

APPLICATIONS

DC/DC Converter







G S N-Channel MOSFET

Parameter Drain-Source Voltage		Symbol	Limit	Unit	
		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	± 20	V	
	T _C = 25 °C		6.5 ^a		
Continuous Drain Current ($T_1 = 150 \ ^{\circ}C$)	T _C = 70 °C		6.0		
	T _A = 25 °C	טי	5.3		
	T _A = 70 °C	1	5.0	A	
Pulsed Drain Current		I _{DM}	25		
	T _C = 25 °C		1.4		
Continuous Source-Drain Diode Current	T _A = 25 °C	IS	0.9 ^{b, c}		
	T _C = 25 °C		1.7		
Maximum Power Dissipation	T _C = 70 °C	P _D	1.1	w	
	T _A = 25 °C	'D	1.1 ^{b, c}	vv	
	T _A = 70 °C	1	0.7 ^{b, c}		
Operating Junction and Storage Temperature	Storage Temperature Range		- 55 to 150		
Soldering Recommendations (Peak Tempera		260	-U		

THERMAL RESISTANCE RATINGS								
Parameter		Symbol	Typical	Maximum	Unit			
Maximum Junction-to-Ambient ^{b, d}	t ≤ 5 s	R _{thJA}	90	115	°C/W			
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	60	75	0/11			

Notes:

a. Package limited

b. Surface Mounted on 1" x 1" FR4 board.

c. t = 5 s.

d. Maximum under steady state conditions is 130 °C/W.

SPECIFICATIONS T _J = 25 °C, unless otherwise noted Parameter Symbol Test Conditions Min. Typ. Max. Unit							
Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
			T	1	I		
-	V _{GS} = 0 V, I _D = 250 μA	30			V		
	I _D = 250 μA		31		mV/°		
			- 5				
V _{GS(th)}		0.7	1.1	2.0	V		
I _{GSS}	$V_{DS} = 0 V$, $V_{GS} = \pm 20 V$			± 100	nA		
I _{DSS}				1 10	μA		
D(an)		10		10	A		
D(01)	50 00	10	0.030				
State Posistance ^a Reg(ar)					Ω		
06					s		
91S	vbs = 10 v, b = 1.0 v		L ''				
			225				
					pF		
	$v_{\rm DS} = 15$ v, $v_{\rm GS} = 0$ v, $i = 1$ MHz						
C _{rss}							
Qg	V _{DS} = 15 V, V _{GS} = 10 V, I _D = 3.4 A			-			
Q _{as}	$V_{DS} = 15 V V_{CS} = 4.5 V I_{D} = 3.4 A$			0.1	nC		
ů.							
	f = 1 MHz	0.8		8.8	Ω		
		0.0					
	$V_{PP} = 15 V R_1 = 56 \Omega$			-	-		
	55 2			-			
					ns		
	$V_{PP} = 15 V R_1 = 56 \Omega$		-		-		
				-			
				-			
			0	10			
1 1	T _C = 25 °C		1	1.4			
	0				A		
	$I_{S} = 2.7 \text{ A}$. $V_{CS} = 0 \text{ V}$		0.8		v		
					ns		
					nC		
	$I_F = 2.7 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, \text{ T}_J = 25 ^\circ\text{C}$			10			
•a			0	1	ns		
	Symbol V _{DS} ΔV _{DS} /TJ ΔV _{GS} (th)/TJ V _{GS} (th) I _{GSS} I _{DSS} I _{D(on)} R _{DS(on)} Gfs C _{iss} C _{oss} C _{rss}	$\begin{tabular}{ c c c c } \hline Symbol & Test Conditions \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A \\ \hline \Delta V_{DS}/T_J & I_D = 250 \ \mu A \\ \hline \Delta V_{GS(th)}/T_J & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A \\ \hline V_{GS}(th) & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A \\ \hline V_{GS}(th) & V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V \\ \hline V_{DS} = 30 \ V, \ V_{GS} = 0 \ V & V_{DS} = 30 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 30 \ V, \ V_{GS} = 0 \ V & T_J = 55 \ ^{\circ}C \\ \hline I_{D(on)} & V_{DS} \ge 5 \ V, \ V_{GS} = 10 \ V \\ \hline V_{GS} = 4.5 \ V, \ I_D = 3.2 \ A \\ \hline V_{DS} = 15 \ V, \ I_D = 2.8 \ A \\ \hline V_{DS} = 15 \ V, \ I_D = 4.8 \ A \\ \hline \hline \\ \hline C_{iss} & V_{DS} = 15 \ V, \ V_{GS} = 0 \ V, \ f = 1 \ MHz \\ \hline \hline \\ C_{iss} & V_{DS} = 15 \ V, \ V_{GS} = 10 \ V, \ I_D = 3.4 \ A \\ \hline \hline \\ \hline \\ Q_{gd} & V_{DS} = 15 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 3.4 \ A \\ \hline \\ \hline \\ Q_{gd} & V_{DS} = 15 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 3.4 \ A \\ \hline \\ \hline \\ Q_{gd} & V_{DS} = 15 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 3.4 \ A \\ \hline \\ \hline \\ Q_{gd} & V_{DS} = 15 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 3.4 \ A \\ \hline \\ \hline \\ Q_{gd} & V_{DD} = 15 \ V, \ R_L = 5.6 \ \Omega \\ I_D \cong 2.7 \ A, \ V_{GEN} = 4.5 \ V, \ R_g = 1 \ \Omega \\ \hline \\ \hline \\ t_d(on) & t_f & V_{DD} = 15 \ V, \ R_L = 5.6 \ \Omega \\ I_D \cong 2.7 \ A, \ V_{GEN} = 10 \ V, \ R_g = 1 \ \Omega \\ \hline \\ \hline \\ t_f & t_{d(onf)} & I_D \cong 2.7 \ A, \ V_{GEN} = 10 \ V, \ R_g = 1 \ \Omega \\ \hline \\ \hline \\ \hline \\ t_f & t_f & V_{DD} = 15 \ V, \ R_L = 5.6 \ \Omega \\ I_D \cong 2.7 \ A, \ V_{GEN} = 10 \ V, \ R_g = 1 \ \Omega \\ \hline \\ \hline \\ \hline \\ t_f & t_f & V_{SD} & I_S = 2.7 \ A, \ V_{GS} = 0 \ V \\ \hline \\$	$\begin{tabular}{ c c c c c } \hline Symbol & Test Conditions & Min. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 30 \\ \hline \Delta V_{DS}/T_J & I_D = 250 \ \mu A & 0.7 \\ \hline I_D = 250 \ \mu A & 0.7 \\ \hline V_{CS}(th) & V_{DS} = V_{GS} \ I_D = 250 \ \mu A & 0.7 \\ \hline I_{CSS} & V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V & V_{DS} = 30 \ V, \ V_{GS} = \pm 20 \ V & V_{DS} = 30 \ V, \ V_{GS} = 0 \ V & T_J = 55 \ ^{\circ}C & 0.5 \\ \hline I_{D}(on) & V_{DS} \ge 5 \ V, \ V_{GS} = 10 \ V & 10 & V_{GS} \ge 5 \ V, \ V_{GS} = 10 \ V & 10 \\ \hline V_{GS} = 10 \ V, \ I_D = 3.2 \ A & V_{DS} = 15 \ V, \ I_D = 2.8 \ A & V_{DS} = 15 \ V, \ I_D = 2.8 \ A & V_{DS} = 15 \ V, \ I_D = 4.8 \ A & V_{DS} = 15 \ V, \ I_D = 4.8 \ A & V_{DS} = 15 \ V, \ V_{GS} = 10 \ V, \ I_D = 3.4 \ A & V_{DS} = 15 \ V, \ V_{GS} = 10 \ V, \ I_D = 3.4 \ A & V_{DS} = 15 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 3.4 \ A & V_{DS} = 15 \ V, \ V_{DS} = 15 \ V, \ V_{CS} = 4.5 \ V, \ I_D = 3.4 \ A & V_{DS} = 15 \ V, \ V_{DS} = 15 \ V, \ V_{DS} = 15 \ V, \ I_D = 3.4 \ A & V_{DS} = 15 \ V, \ V_{DS} = 15 \ V, \ V_{CS} = 10 \ V, \ I_D = 3.4 \ A & V_{DS} = 15 \ V, \ V_{DS} = 10 \ V, \ I_D = 3.4 \ A & V_{DS} = 10 \ V, \ I_D = 3.4 \ A & V_{DS} = 10 \ V, \ I_D = 15 \ V, \ R_L = 5.6 \ \Omega & V_{DS} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 15 \ V, \ R_g = 1 \ \Omega & V_{DD} = 15 \ V, \ R_g = 1 \ \Omega & V_{DD} = 15 \ V, \ R_g = 1 \ \Omega & V_{DD} = 15 \ V, \ R_g = 1 \ \Omega & V_{DD} = 15 \ V, \ R_g = 1 \ \Omega & V_{DS} = 10 \ V, \ R_g = 1 \ \Omega & V_{DS} & V_{DS} & I_S = 2.7 \ A, \ V_{GS} = 0 \ V & V_{SD} & I_S = 2.7 \ A, \ V_{GS} = 0 \ V & V_{SD} & I_S = 2.7 \ A, \ V_{GS} = 0 \ V & V_{SD} & I_S = 2.7 \ A, \ V_{GS} = 0 \ V & V_{SD} & I_S = 2.7 \ A, \ V_{GS} = 0 \ V & V_{SD} & I_S = 2.7 \ A, \ V_{GS} = 0 \ V & V_{SD} & I_S = 2.7 \ A, \ V_{SD} = 0 \ V & V_{SD} & I_S = 2.7 \ A, \ V_{SD} = 0 \ V & V_{SD} & I_S = 2.7 \ A, \ $	$\begin{tabular}{ c c c c c } \hline Symbol & Test Conditions & Min. Typ. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 30 & 31 & 31 & 31 & 30 & 31 & 31 & 30 & 31 & 31$	$\begin{tabular}{ c c c c c c } \hline Test Conditions & Min. Typ. Max. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 30 & 31 & -5 & -5 & -5 & -5 & -5 & -5 & -5 & -$		

Notes:

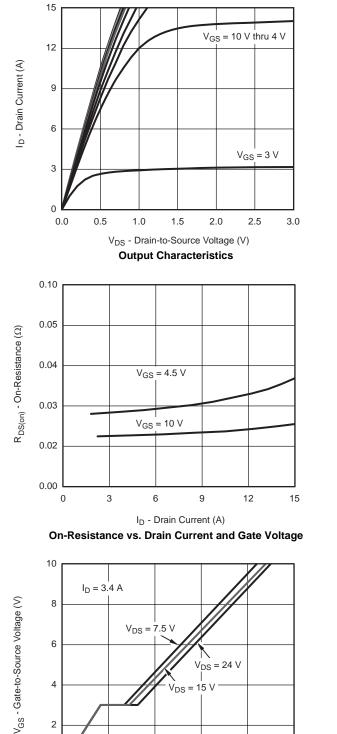
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing.

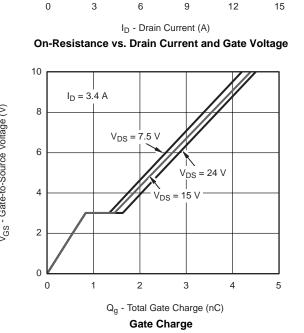
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

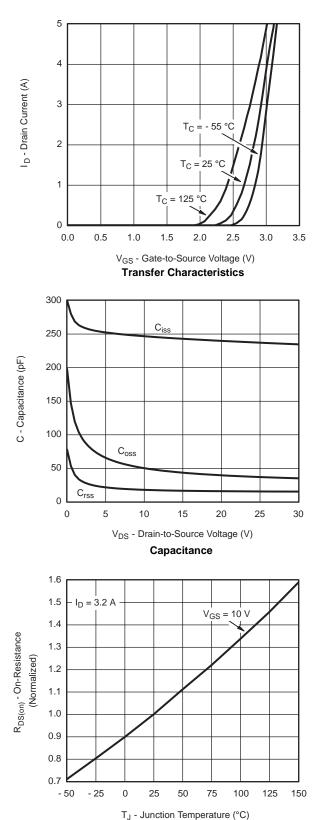
VBsemi Bsemi.com





TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

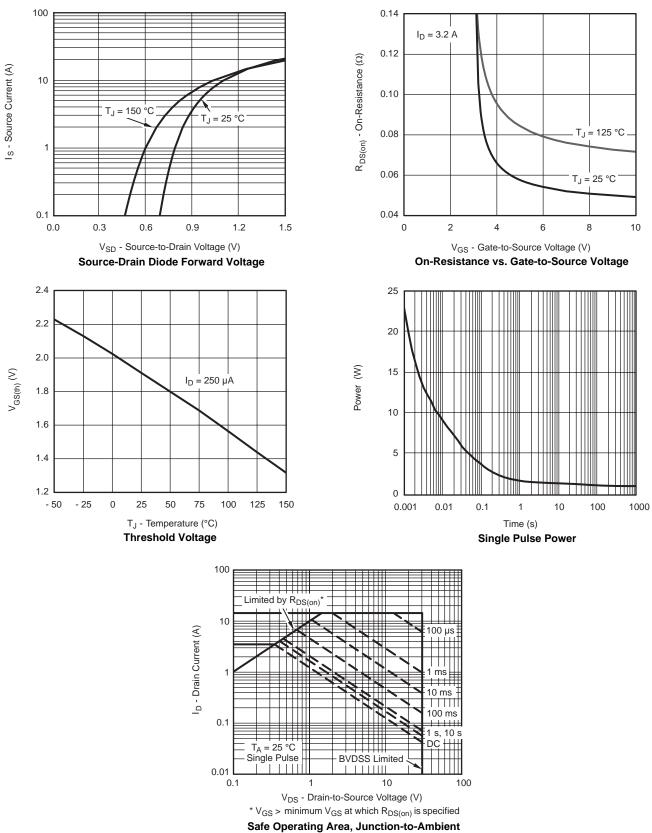




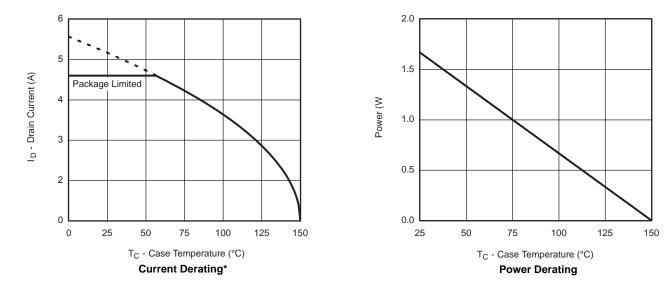
On-Resistance vs. Junction Temperature











TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

* The power dissipation P_D is based on $T_{J(max)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



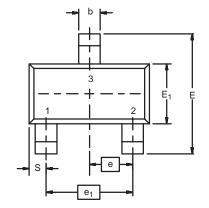




Normalized Thermal Transient Impedance, Junction-to-Foot



SOT-23 (TO-236): 3-LEAD







Dim	MILLIN	METERS	INCHES		
	Min	Max	Min	Мах	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
C	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	
ECN: S-03946-Rev. K, 09- DWG: 5479	Jul-01				



RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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